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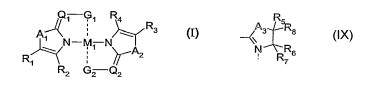
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(54) Title: OPTICAL RECORDING MATERIALS HAVING HIGH STORAGE DENSITY



(57) Abstract: The invention relates to an optical recording medium comprising a substrate, a reflecting layer and a recording layer based on compounds of formula (I) wherein G_1 and G_2 are each independently of the other, A_1 and A_2 are each independently of the other $N(R_{12})$, O, S or Se and A_3 is $C(C_1-C_5alkyI)_2$, $C(C_4-C_5$ alkylene), $N(R_{12})$, O, S, Se, N= $C(R_{13})$ or unsubstituted or R_{14} -substituted CH=CH; M_1 is a transition metal of groups (IX) to (XII), preferably CO, Cu, Ni, Pd or Zn, especially CO, CU or Ni; CU and CU are each independently of the other $C(R_{15})$, CU or CU. For the detailed definitions of the further substituents, see the description. Recording and playback are effected especially at a wavelength of from 350 to

500 nm, for example using a blue laser. The recording and playback quality is excellent and allows a high storage density. Also claimed are new compounds of formula (I), with the exception of the compounds disclosed in J. Org. Chem. 67/16, 5753-5772 [2002].

Optical recording materials having high storage density

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The invention relates to new optical recording materials that have excellent recording and playback quality especially at a wavelength of 350-500 nm. Recording and playback can be effected very advantageously with high sensitivity at the same wavelength, and the storage density that is achievable is significantly higher than in the case of known materials. In addition, the materials according to the invention have very good storage properties before and after recording, even under especially harsh conditions, such as exposure to sunlight or fluorescent lighting, heat and/or high humidity. In addition, their manufacture is simple and readily reproducible using customary coating processes, such as spin-coating.

WO 02/082438 discloses the use of ionic salts, including those with metal complex anions, for optical recording materials. Those colorants are always substituted by alkyl, alkenyl, aryl or heteroaryl at the nitrogen atom. Their optical properties do not, however, fully satisfy increased demands. In particular, the refractive index as well as the absorption and the steepness of the absorption band on its long wavelength flank in the solid still leave something to be desired.

JP-A-11/34500, JP-A-11/92479 and EP-A-0 903 733 disclose metal and boron

complexes of colorants of formulae N and N

recording materials such as CD-R or DVD-R. Here too, however, the optical

properties, especially the spectral properties in or near the UV range that are necessary for the highest possible storage densities, and the information density per unit surface area are not able to satisfy the highest demands as desired. The information density per unit surface area is far lower than is desirable.

5 Conventional optical recording materials therefore satisfy high demands only to some extent, or do not satisfy all demands to an entirely satisfactory degree at the same time.

On the other hand, J. Org. Chem. 67/16, 5753-5772 [2002] describes the synthesis of a number of bis(o-azaheteroaryl)methanes and their coordination properties with respect to divalent transition metals, heteroaryl being 1,3-azol-2-yl, 1,3-benzazol-2-yl and azinyl and the transition metals being Zn, Cu, Co, Ni, Hg and Pd. Inter alia 2:1 salt complexes of bis(benzothiazol-2-yl)methane and bis(benzoxazol-2-yl)methane with copper(II) chloride and nickel(II) sulfate, and cobalt(II) chloride and palladium(II) nitrate are disclosed, whereas bis(thiazol-2-yl)methane yields, with deprotonation, neutral 2:1 chelates with Zn(II), Cu(II), Ni(II) and Co(II). All substances are strongly coloured.

The aim of the invention is an optical recording medium having high information density, sensitivity and data reliability. Such a recording medium should be robust, durable and easy to use. Furthermore, it should be inexpensive to manufacture as a mass-produced product and should require equipment that is as small and inexpensive as possible.

The invention therefore relates to an optical recording medium comprising a substrate, a recording layer and optionally one or more reflecting layers, wherein the

recording layer comprises a compound of formula

25 tautomer thereof, wherein

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G₁ and G₂ are each independently of the other

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 A_1 and A_2 are each independently of the other N(R₁₂), O, S or Se and A_3 is C(C₁-C₅alkyl)₂, C(C₄-C₅alkylene), N(R₁₂), O, S, Se, N=C(R₁₃) or unsubstituted or R₁₄-substituted CH=CH;

 M_1 is a transition metal of groups IX to XII, preferably Co, Cu, Ni, Pd or Zn, especially Co, Cu or Ni;

 Q_1 and Q_2 are each independently of the other $C(R_{15})$, N or P;

R₁, R₂, R₃, R₄, R₅, R₆, R₇, R₈ and R₁₄ are each independently of the others

10 hydrogen, R₁₈, or C₆-C₁₂aryl, C₄-C₁₂heteroaryl, C₇-C₁₂aralkyl or C₅-C₁₂heteroaralkyl each unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₈; or

R₁ and R₂, R₃ and R₄, R₅ and R₆, R₅ and R₁₃ and/or R₅ and R₁₄, together in pairs, are C₃-C₆alkylene or C₃-C₆alkenylene, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₇ and may be uninterrupted or interrupted by O, S or N(R₁₂), or 1,4-buta-1,3-dienylene,

applicable identical or different, radicals R_{18} and in which 1 or 2 carbon atoms may have been replaced by nitrogen;

WO 2004/079732

 R_9 , R_{12} and R_{13} are each independently of the others C_1 - C_2 4alkyl, C_3 - C_2 4cycloalkyl, C_2 - C_2 4alkyl-[O- C_1 - C_4 alkyl-[O- C_1 - C_4 4alkyl-[NH- C_1 - C_4 4alkylene]_m, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R_{17} ; or C_6 - C_{12} aryl, C_4 - C_{12} heteroaryl,

5 C₇-C₁₂aralkyl or C₅-C₁₂heteroaralkyl, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₈;

 R_{10} , R_{11} and R_{18} are each independently of the others halogen, nitro, cyano, thiocyanato, hydroxy, $O\text{-}R_{19}$, $O\text{-}CO\text{-}R_{19}$, $S\text{-}R_{19}$, CHO, COR_{20} , CHOR $_{19}OR_{23}$, $CR_{20}OR_{19}OR_{23}$, R_{16} , $N\text{=}N\text{-}R_{16}$, $N\text{=}CR_{19}R_{20}$, $N\text{=}CR_{21}R_{22}$, $C(R_{15})\text{=}NR_{19}$,

 $\begin{array}{lll} 10 & C(R_{15}) = NR_{21}, \, C(R_{15}) = CR_{21}R_{22}, \, NH_2, \, NH-R_{19}, \, NR_{19}R_{20}, \, NH_3^+, \, NH_2R_{19}^+, \, NHR_{19}R_{20}^+, \\ & NR_{19}R_{20}R_{23}^+, \, CONH_2, \, CONHR_{19}, \, CONR_{19}R_{20}, \, SO_2R_{19}, \, SO_2NH_2, \, SO_2NHR_{19}, \\ & SO_2NR_{19}R_{20}, \, COOH, \, COOR_{19}, \, OCOOR_{19}, \, NHCOR_{19}, \, NR_{19}COR_{23}, \, NHCOOR_{19}, \\ & NR_{19}COOR_{23}, \, ureido, \, NR_{19}-CO-NHR_{23}, \, B(OH)_2, \, B(OH)(OR_{19}), \, B(OR_{19})OR_{23}, \\ & phosphato, \, PR_{19}R_{23}, \, POR_{19}OR_{23}, \, P(=O)OR_{19}OR_{23}, \, OPR_{19}R_{23}, \, OPR_{19}OR_{23}, \\ \end{array}$

OP(=O)R₁₉OR₂₃, OP(=O)OR₁₉OR₂₃, OPO₃R₁₉, sulfato, sulfo, or C₁-C₁₂alkyl, C₃-C₁₂cycloalkyl, C₁-C₁₂alkylthio, C₃-C₁₂cycloalkylthio, C₁-C₁₂alkoxy or C₃-C₁₂cycloalkoxy each unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₇;

R₁₅ is hydrogen, cyano, hydroxy, C₁-C₁₂alkoxy, C₃-C₁₂cycloalkoxy, C₁-C₁₂alkylthio,

C₃-C₁₂cycloalkylthio, amino, NHR₂₄, NR₂₅R₂₆, R₂₇, halogen, nitro, formyl, N=N-R₂₇,

C(R₁₄)=CR₂₁R₂₂, C(R₁₄)=NR₁₉, COO-R₂₅, carboxy, carbamoyl, CONH-R₂₅,

CONR₂₅R₂₆, N=CR₁₉R₂₀, or C₁-C₁₂alkyl, C₃-C₁₂cycloalkyl, C₂-C₁₂alkenyl or

C₃-C₁₂cycloalkenyl each unsubstituted or substituted by one or more, where applicable identical or different, halogen, hydroxy, C₁-C₁₂alkoxy or C₃-C₁₂cycloalkoxy

radicals;

 R_{16} is C_6 - C_{12} aryl, C_4 - C_{12} heteroaryl, C_7 - C_{12} aralkyl or C_6 - C_{12} heteroaralkyl, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R_{26} ;

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 R_{17} is halogen, hydroxy, $O-R_{25}$, $O-CO-R_{25}$, $S-R_{25}$, NH_2 , $NH-R_{25}$, $NR_{25}R_{26}$, NH_3^{\dagger} , $NH_2R_{25}^{\dagger}$, $NH_{25}R_{26}^{\dagger}$, $NR_{24}R_{25}R_{26}^{\dagger}$, $NR_{25}-CO-R_{24}$, $NR_{25}COOR_{24}$, cyano, formyl, $COO-R_{25}$, carboxy, carbamoyl, $CONH-R_{25}$, $CONR_{25}R_{26}$, ureido, $NH-CO-NHR_{24}$, $NR_{25}-CO-NHR_{24}$, phosphato, $PR_{25}R_{24}$, $POR_{25}OR_{24}$, $P(=O)OR_{25}OR_{24}$, $OPR_{25}R_{24}$, $OPR_{25}OR_{24}$, OP

R₁₉, R₂₀ and R₂₃ are each independently of the others R₁₆, or C₁-C₁₂alkyl,
C₃-C₁₂cycloalkyl, C₂-C₁₂alkenyl or C₃-C₁₂cycloalkenyl each unsubstituted or
substituted by one or more, where applicable identical or different, halogen, hydroxy,
C₁-C₁₂alkoxy or C₃-C₁₂cycloalkoxy radicals; or

 R_{14} and R_{19} together, R_{15} and R_{19} together and/or R_{19} and R_{23} together are $C_2\text{-}C_{12}$ alkylene, $C_3\text{-}C_{12}$ cycloalkylene, $C_2\text{-}C_{12}$ alkenylene or $C_3\text{-}C_{12}$ cycloalkenylene, each of which is unsubstituted or substituted by one or more, where applicable identical or different, halogen, hydroxy, $C_1\text{-}C_{12}$ alkoxy or $C_3\text{-}C_{12}$ cycloalkoxy radicals; or

 R_{19} and R_{20} together with the common nitrogen are pyrrolidine, piperidine, piperazine or morpholine, each of which is unsubstituted or mono- to tetra-substituted by C_1 - C_4 alkyl; or carbazole, phenoxazine or phenothiazine, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R_{28} ;

 R_{21} and R_{22} are each independently of the other NR₂₅R₂₆, CN, CONH₂, CONHR₁₉, CONR₁₉R₂₀ or COOR₂₀;

R₂₄, R₂₅ and R₂₆ are each independently of the others C₁-C₁₂alkyl, C₃-C₁₂cycloalkyl,

C₂-C₁₂alkenyl, C₃-C₁₂cycloalkenyl, C₆-C₁₂aryl, C₄-C₁₂heteroaryl, C₇-C₁₂aralkyl or

C₅-C₁₂heteroaralkyl; or

-6-

 R_{25} and R_{26} together with the common nitrogen are pyrrolidine, piperidine, piperazine or morpholine, each of which is unsubstituted or mono- to tetra-substituted by C_1 - C_4 alkyl;

R₂₇ is C₆-C₁₂aryl, C₄-C₁₂heteroaryl, C₇-C₁₂aralkyl or C₅-C₁₂heteroaralkyl, each of
 which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₈;

 R_{28} is nitro, SO_2NHR_{25} , $SO_2NR_{25}R_{26}$, or C_1 - C_{12} alkyl, C_3 - C_{12} cycloalkyl, C_1 - C_{12} alkylthio, C_3 - C_{12} cycloalkylthio, C_1 - C_{12} alkoxy or C_3 - C_{12} cycloalkoxy each unsubstituted or substituted by one or more, where applicable identical or different, radicals R_{17} ; and

10 m is a number from 1 to 10.

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When R_5 forms a bridge with R_6 , R_5 may not at the same time form a bridge with R_{13} or R_{14} .

It will be understood that acidic groups, such as carboxy, sulfo, sulfato and phosphato, may also be in the form of a salt, for example an alkali metal, alkaline earth metal, ammonium or phosphonium salt, such as Li[†], Na[†], K[†], Mg^{2†}, Ca^{2†}, Cu^{2†}, Ni^{2†}, Fe^{2†}, Co^{2†}, Zn^{2†}, Sn^{2†}, La^{3†}, ammonium, methylammonium, ethylammonium, isopropylammonium, [™]Primene 81-R, [™]Rosin Amine D, pentadecylammonium, [™]Primene JM-T, dicyclohexylammonium, tetramethylammonium, tetraethylammonium, tetraethylammonium, benzyltriethylammonium, methyltrioctylammonium, tridodecylmethylammonium, tetrabutylphosphonium, tetraphenylphosphonium, butyltriphenylphosphonium or ethyltriphenylphosphonium, or any of the cations B-1 to B-169 mentioned in US-6 225 024, to which individually reference is expressly made here.

Halogen is chlorine, bromine, fluorine or iodine, preferably fluorine or chlorine,
 especially fluorine on alkyl (for example trifluoromethyl, α,α,α-trifluoroethyl or perfluorinated alkyl groups, such as heptafluoropropyl) and chlorine on aryl,

WO 2004/079732

heteroaryl or on the aryl moiety of aralkyl or on the heteroaryl moiety of heteroaralkyl.

Alkyl, cycloalkyl, alkenyl or cycloalkenyl can be straight-chain or branched, or monocyclic or polycyclic. Alkyl is, for example, methyl, straight-chain C₂-C₂₄alkyl or preferably branched C₃-C₂₄alkyl. Alkenyl is, for example, straight-chain C₂-C₂₀alkenyl or preferably branched C₃-C₂₄alkenyl. The invention therefore relates especially also to compounds of formula (I) containing branched C₃-C₂₄alkyl or branched C₃-C₂₄alkenyl, and also to optical recording materials comprising such compounds. C₁-C₂₄Alkyl is therefore, for example, methyl, ethyl, n-propyl, isopropyl, n-butyl, sec-butyl, isobutyl, tert-butyl, n-pentyl, 2-pentyl, 3-pentyl, 2,2-dimethylpropyl, n-hexyl, n-octyl, 1,1,3,3-tetramethylbutyl, 2-ethylhexyl, nonyl, decyl, dodecyl, tetradecyl, hexadecyl, octadecyl, eicosyl, heneicosyl, docosyl or tetracosyl. C₃-C₂₄Cycloalkyl is, for example, cyclopropyl, cyclobutyl, cyclopentyl, cyclohexyl, trimethylcyclohexyl, menthyl, thujyl, bornyl, 1-adamantyl or 2-adamantyl.

C₂-C₂₀Alkenyl and C₃-C₂₀cycloalkenyl are C₂-C₂₀alkyl and C₃-C₂₀cycloalkyl that is mono- or poly-unsaturated, wherein two or more double bonds may be isolated or conjugated, for example vinyl, allyl, 2-propen-2-yl, 2-buten-1-yl, 3-buten-1-yl, 1,3-butadien-2-yl, 2-cyclobuten-1-yl, 2-penten-1-yl, 3-penten-2-yl, 2-methyl-1-buten-3-yl, 2-methyl-3-buten-2-yl, 3-methyl-2-buten-1-yl, 1,4-pentadien-3-yl, 2-cyclopenten-1-yl, 2-cyclohexen-1-yl, 3-cyclohexen-1-yl, 2,4-cyclohexadien-1-yl, 1-p-menthen-8-yl, 4(10)-thujen-10-yl, 2-norbornen-1-yl, 2,5-norbornadien-1-yl, 7,7-dimethyl-2,4-norcaradien-3-yl or the various isomers of hexenyl, octenyl, nonenyl, decenyl, dodecenyl, tetradecenyl, hexadecenyl, octadecenyl, eicosenyl, heneicosenyl, docosenyl, tetradecadienyl, hexadecadienyl, nonadienyl, decadienyl, dodecadienyl, tetradecadienyl, hexadecadienyl, octadecadienyl or eicosadienyl.

 C_7 - C_{12} Aralkyl is, for example, benzyl, 2-benzyl-2-propyl, β -phenyl-ethyl, 9-fluorenyl, α , α -dimethylbenzyl, ω -phenyl-butyl or ω -phenyl-hexyl. When C_7 - C_{12} aralkyl is substituted, both the alkyl moiety and the aryl moiety of the aralkyl group can be

- 8 -

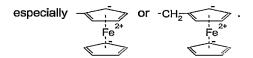
substituted, the latter alternative being preferred.

C₆-C₁₂Aryl is, for example, phenyl, naphthyl, biphenylyl or 2-fluorenyl.

C₄-C₁₂Heteroaryl is an unsaturated or aromatic radical having 4n+2 conjugated π-electrons, for example 2-thienyl, 2-furyl, 2-pyridyl, 2-thiazolyl, 2-oxazolyl,
 2-imidazolyl, isothiazolyl, triazolyl or any other ring system consisting of thiophene, furan, pyridine, thiazole, oxazole, imidazole, isothiazole, triazole, pyridine and benzene rings and unsubstituted or substituted by from 1 to 6 ethyl, methyl, ethylene and/or methylene substituents, for example benzotriazolyl, and in the case of N-heterocycles where applicable also those in the form of their N-oxides.

10 C₅-C₁₂Heteroaralkyl is, for example, C₁-C₈alkyl substituted by C₄-C₁₁heteroaryl.

Furthermore, aryl and aralkyl can also be aromatic groups bonded to a metal, for example in the form of metallocenes of transition metals known *per se*, more



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The transition metal M₁ is preferably in the form of a doubly positively charged cation, for example Co²⁺, Cu²⁺, Ni²⁺, Pd²⁺ or Zn²⁺, especially Co²⁺, Cu²⁺ or Ni²⁺.

The compound of formula (I) may also be a cation which has been neutralised with an inorganic, organic or organometallic anion, for example when one or more ammonium groups are present or when the transition metal has one or more excess positive charges, such as in Co³⁺. The inorganic, organic or organometallic anion may be, for example, the anion of a mineral acid, of the conjugated base of an organic acid (for example an alcoholate, phenolate, carboxylate, sulfonate or phosphonate) or an organometallic complex anion, for example fluoride, chloride, bromide, iodide, perchlorate, periodate, nitrate, hydrogen carbonate, ½ carbonate, ½ sulfate, C₁-C₄alkyl sulfate, hydrogen sulfate, ½ phosphate, ½ hydrogen phos-

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phate, dihydrogen phosphate, $\frac{1}{2}$ C₁-C₄alkanephosphonate, C₁-C₄alkane-C₁-C₁₂alkyl-phosphonate, di-C₁-C₄alkylphosphinate, tetrafluoroborate, hexafluorophosphate, hexafluoroantimonate, acetate, trifluoroacetate, heptafluorobutyrate, $\frac{1}{2}$ oxalate, methanesulfonate, trifluoromethanesulfonate, benzenesulfonate, tosylate, p-chlorobenzenesulfonate, p-nitrobenzenesulfonate, phenolate, benzoate or a

The person skilled in the art will readily recognise that it is also possible to use other anions with which he is familiar. It will be self-evident to him that $\frac{1}{x}$ of an inorganic, organic or organometallic anion having x negative charges, for example $\frac{1}{2} \cdot SO_4^{2-}$, is a multiply charged anion which neutralises several singly charged cations or a cation having x charges, as the case may be.

Phenolates or carboxylates are, for example, of formula

negatively charged metal complex.

$$R_{30}$$
 O^- or R_{31} O^- (wherein R_{29} , R_{30} and R_{31} are each independently

of the others hydrogen, R_{18} , or C_6 - C_{12} aryl, C_4 - C_{12} heteroaryl, C_7 - C_{12} aralkyl or C_6 - C_{12} heteroaralkyl each unsubstituted or substituted by one or more, where applicable identical or different, radicals R_{18} , for example anions of C_1 - C_{12} alkylated, especially tert- C_4 - C_8 alkylated, phenols and benzoic acids, such as

Preference is given to compounds of formula (I) wherein

20 A_1 , A_2 and A_3 are each independently of the others O, S or N(R₁₂) and/or Q₁ and Q₂ are C(R₁₅) or N;

 G_1 and G_2 are each independently of the other $A_3 + A_5 + A_6 + A_5 + A_6 +$

R₁, R₂, R₃, R₄, R₅, R₆, R₇, R₈ and R₁₄ are each independently of the others hydrogen, R₁₈, or C₆-C₁₂aryl or C₇-C₁₂aralkyl each unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₈;

 R_9 , R_{12} and R_{13} are each independently of the others unsubstituted or R_{17} -substituted C_1 - C_8 alkyl;

 R_{10} and R_{18} are each independently of the other halogen, nitro, cyano, O-R₁₉, formyl, CH=C(CN)₂, CH=C(CN)CONH₂, CH=C(CN)CONHR₁₉, CH=C(CN)CONR₁₉R₂₀,

- 10 CH=C(CN)COOR₁₉, CH=C(COOR₁₉)COOR₂₀, CONH₂, CONHR₁₉, CONR₁₉R₂₀, SO₂C₁-C₁₂alkyl, SO₂NH₂, SO₂NHR₁₉, SO₂NR₁₉R₂₀, COOH, COOR₁₉, NHCOR₁₉, NR₁₉COR₂₃, NHCOOR₁₉, NR₁₉COOR₂₃, ureido, P(=O)OR₁₉OR₂₃, sulfo, or C₁-C₁₂alkyl, C₁-C₁₂alkylthio or C₁-C₁₂alkoxy each unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₇;
- 15 R₁₅ is hydrogen, cyano, halogen, nitro, formyl, N=N-R₂₇, C(R₁₄)=CR₂₁R₂₂, C(R₁₄)=NR₁₉, COO-R₂₅, carboxy, carbamoyl, CONH-R₂₅, CONR₂₅R₂₆, or C₁-C₁₂alkyl unsubstituted or substituted by one or more halogen substituents;

 R_{16} is unsubstituted or substituted C_6 - C_{12} aryl or C_7 - C_{12} aralkyl, especially a metallocenyl radical;

20 R₁₇ is halogen, hydroxy, O-R₂₅, amino, NH-R₂₅, NR₂₅R₂₆, NR₂₅-CO-R₂₄, NR₂₅COOR₂₄, cyano, COO-R₂₅, carboxy, CONH-R₂₅, CONR₂₅R₂₆, sulfato, sulfo, or C₁-C₁₂alkoxy unsubstituted or mono- or poly-substituted by halogen;

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 R_{19} , R_{20} and R_{23} are each independently of the others C_1 - C_{12} alkyl unsubstituted or substituted by one or more, where applicable identical or different, halogen, hydroxy or C_1 - C_{12} alkoxy radicals, or unsubstituted C_6 - C_{12} aryl or C_7 - C_{12} aralkyl; or

R₁₉ and R₂₀ together with the common nitrogen are morpholine, or piperidine N-substituted by C₁-C₄alkyl;

 R_{25} , R_{26} and R_{24} are each independently of the others C_1 - C_{12} alkyl, C_2 - C_{12} alkenyl, C_6 - C_{12} aryl or C_7 - C_{12} aralkyl; or

 R_{25} and R_{26} together with the common nitrogen are morpholine, or piperidine N-substituted by C_1 - C_4 alkyl; and/or

10 m is a number from 1 to 4.

Special preference is given to compounds of formula (I) wherein Q₁ and Q₂ are

$$C(R_{15}); G_1 \text{ and } G_2 \text{ are } \overset{A_3}{\longleftarrow} R_{18}; \text{ and } A_1, A_2 \text{ and } A_3 \text{ are } O, S \text{ or } N(R_{12});$$

R₁₂ is C₁-C₂₄alkyl, C₁-C₄alkyl-[O-C₁-C₄alkylene]_m or C₁-C₄alkyl-[NH-C₁-C₄alkylene]_m, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₇, or C₆-C₁₂aryl unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₈;

R₁₅ is hydrogen, cyano, COO-R₂₅ or C₁-C₁₂alkyl;

R₁₇ is halogen, hydroxy, O-R₂₅, cyano, COO-R₂₅ or carboxy; and

R₁₈ is halogen, nitro, cyano, O-R₁₉, CH=C(CN)₂, COOR₁₉, ureido, CONR₂₅R₂₆, 20 SO₂R₂₅, P(=O)OR₁₉OR₂₃ or unsubstituted or substituted C₁-C₁₂alkyl.

Those preferred meanings apply both individually and in any combination. The compounds of formula (I) generally exhibit more advantageous properties, the more

preferred individual features they have.

Also preferred are compounds of formula (I) wherein R_1 and/or R_2 is/are R_2 is/are R_3 is/are R_2 is R_3 is R_4 is R_5 is R_5

The recording layer advantageously comprises a compound of formula (I) or a mixture of such compounds as main component, for example at least 30 % by weight, preferably at least 60 % by weight, especially at least 80 % by weight.

Further customary constituents are possible, for example other chromophores (for example those disclosed in WO 01/75873, or others having an absorption maximum at from 300 to 1000 nm), stabilisers, ${}^{1}O_{2}$ -, triplet- or luminescence-quenchers, melting-point reducers, decomposition accelerators or any other additives that have already been described in optical recording media. Preferably, stabilisers or fluoresence-quenchers are added if desired.

When the recording layer comprises further chromophores, the amount of such

- 13 -

chromophores should preferably be small, so that the absorption thereof at the wavelength of the inversion point of the longest-wavelength flank of the absorption of the entire solid layer is a fraction of the absorption of the pure compound of formula (I) in the entire solid layer at the same wavelength, advantageously at most 1/3, preferably at most 1/5, especially at most 1/10. The absorption maximum is preferably higher than 425 nm, especially higher than 500 nm.

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Stabilisers, ¹O₂-, triplet- or luminescence-quenchers are, for example, metal complexes of N- or S-containing enolates, phenolates, bisphenolates, thiolates or bisthiolates or of azo, azomethine or formazan dyes, such as bis(4-dimethylaminodithiobenzil)nickel [CAS Nº 38465-55-3], ®Irgalan Bordeaux EL, ®Cibafast N or 10 similar compounds, hindered phenols and derivatives thereof (optionally also as counter-ions X), such as [®]Cibafast AO, o-hydroxyphenyl-triazoles or -triazines or other UV absorbers, such as [®]Cibafast W or [®]Cibafast P or hindered amines (TEMPO or HALS, also as nitroxides or NOR-HALS, optionally also as counter-ions 15 X), and also as cations diimmonium, Paraquat™ or Orthoguat™ salts, such as [®]Kayasorb IRG 022, [®]Kayasorb IRG 040, optionally also as radical ions, such as N,N,N',N'-tetrakis(4-dibutylaminophenyl)-p-phenyleneamine-ammonium hexafluorophosphate, hexafluoroantimonate or perchlorate. The latter are available from Organica (Wolfen / DE); [®]Kayasorb brands are available from Nippon Kayaku Co. Ltd., and [®]Irgalan and [®]Cibafast brands are available from Ciba Spezialitätenchemie 20 AG.

Many such structures are known, some of them also in connection with optical recording media, for example from US-5 219 707, JP-A-06/199045, JP-A-07/76169, JP-A-07/262604 or JP-A-2000/272241. They may be, for example, salts of the metal complex anions disclosed above with any desired cations, for example the cations disclosed above, or metal complexes, illustrated, for example, by a compound of

- 14 -

formula or
$$\begin{array}{c} C_4H_9 \\ S--Ni--NH_2 \\ O \end{array} .$$

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The person skilled in the art will know from other optical information media, or will easily identify, which additives in which concentration are particularly well suited to which purpose. Suitable concentrations of additives are, for example, from 0.001 to 1000% by weight, preferably from 1 to 50% by weight, based on the recording medium of formula (I).

The optical recording materials according to the invention exhibit excellent spectral properties of the solid amorphous recording layer. The refractive index is extraordinarily high, in some cases even above 2.5. By virtue of an aggregation tendency in the solid that is surprisingly low for such compounds, the absorption band is narrow and intense, the absorption band being especially steep on the long-wavelength side. Crystallites are unexpectedly and very advantageously not formed or are formed only to a negligible extent. The reflectivity of the layers in the range of the writing and reading wavelength is very high in the unwritten state.

15 By virtue of those excellent layer properties it is possible to obtain a rapid optical recording having high sensitivity, high reproducibility and geometrically very precise mark boundaries, the refractive index and the reflectivity changing substantially, which gives a high degree of contrast. The differences in the mark lengths and the interval distances ("jitter") are very small, which enables a high storage density to be obtained using a relatively thin recording channel with a narrow track spacing ("pitch"). In addition, the recorded data are played back with an astonishingly low error rate, so that error correction requires only a small amount of storage space.

By virtue of the excellent solubility, including in apolar solvents, solutions can be

used even in high concentrations without troublesome precipitation, for example during storage, so that problems during spin-coating are largely eliminated. This applies especially to compounds containing branched C₃-C₈alkyl.

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Recording and playback can take place at the same wavelength, therefore advantageously requiring a simple optical system with a single laser source of advantageously from 350 to 500 nm, preferably from 370 to 450 nm. Especially preferred is the UV range from 370 to 390 nm, especially approximately 380 nm, or especially at the edge of the visible range of from 390 to 430 nm, more especially approximately 405±5 nm. In the field of compact, blue or violet laser diodes (such as Nichia GaN 405 nm) with an optical system of high numerical aperture the marks can be so small and the tracks so narrow that up to about 20 to 25 Gb per recording layer is achievable on a 120 mm disc. At 380 nm it is possible to use indium-doped UV-VCSELs (Vertical-Cavity Surface-Emitting Laser), which laser source already exists as a prototype [Jung Han et al., see MRS Internet J. Nitride Semicond. Res. 5S1, W6.2 (2000)].

The invention therefore relates also to a method of recording or playing back data, wherein the data on an optical recording medium according to the invention are recorded or played back at a wavelength of from 350 to 500 nm.

The recording medium is based on the structure of known recording media and is, for example, analogous to those mentioned above. It may be composed, for example, of a transparent substrate, a recording layer comprising at least one of the compounds of formula (I), a reflector layer and a covering layer, the writing and readout being effected through the substrate.

Suitable substrates are, for example, glass, minerals, ceramics and thermosetting and thermoplastic plastics. Preferred supports are glass and homo- or co-polymeric plastics. Suitable plastics are, for example, thermoplastic polycarbonates, polyamides, polyesters, polyacrylates and polymethacrylates, polyurethanes, polyolefins, polyvinyl chloride, polyvinylidene fluoride, polyimides, thermosetting polyesters and

epoxy resins. Special preference is given to polycarbonate substrates which can be produced, for example, by injection-moulding. The substrate can be in pure form or may comprise customary additives, for example UV absorbers or dyes, as proposed e.g. in JP-A-04/167239 as light stabilisation for the recording layer. In the latter case it may be that in the range of the writing wavelength (emission wavelength of the laser) the dye added to the support substrate has no or at most only very low absorption, preferably up to a maximum of about 20% of the laser light focussed onto the recording layer.

The substrate is advantageously transparent over at least a portion of the range from 350 to 500 nm, so that it is permeable to, for example, at least 80 % of the incident light of the writing or readout wavelength. The substrate is advantageously from 10 µm to 2 mm thick, preferably from 100 to 1200 µm thick, especially from 600 to 1100 µm thick, with a preferably spiral guide groove (track) on the coating side, a groove depth of from 10 to 200 nm, preferably from 80 to 150 nm, a groove width of from 100 to 400 nm, preferably from 150 to 250 nm, and a spacing between two turns of from 200 to 600 nm, preferably from 350 to 450 nm. Grooves of different cross-sectional shape are known, for example rectangular, trapezoidal or V-shaped. Analogously to the known CD-R and DVD-R media, the guide groove may additionally undergo a small periodic or quasi-periodic lateral deflection (wobble), so that synchronisation of the speed of rotation and the absolute positioning of the reading head (pick-up) are made possible. Instead of, or in addition to, the deflection, the same function can be performed by markings between adjacent grooves (pre-pits).

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The recording medium is applied, for example, by application of a solution by spin-coating, the objective being to produce a layer that is as amorphous as possible, the thickness of which layer is advantageously from 0 to 40 nm, preferably from 1 to 20 nm, especially from 2 to 10 nm, on the surface ("land") and, depending upon the geometry of the groove, advantageously from 20 to 150 nm, preferably from 50 to 120 nm, especially from 60 to 100 nm, in the groove.

- 17 -

Reflecting materials suitable for the reflector layer include especially metals, which provide good reflection of the laser radiation used for recording and playback, for example the metals of Main Groups III, IV and V and of the Sub-Groups of the Periodic Table of the Elements. Al, In, Sn, Pb, Sb, Bi, Cu, Ag, Au, Zn, Cd, Hg, Sc, Y, La, Ti, Zr, Hf, V, Nb, Ta, Cr, Mo, W, Fe, Co, Ni, Ru, Rh, Pd, Os, Ir, Pt and the lanthanide metals Ce, Pr, Nd, Pm, Sm, Eu, Gd, Tb, Dy, Ho, Er, Tm, Yb and Lu and alloys thereof are especially suitable. On account of its high reflectivity and ease of production special preference is given to a reflective layer of aluminium, silver, gold or an alloy thereof (for example a white gold alloy), especially aluminium on economic and ecological grounds. The reflector layer is advantageously from 5 to 200 nm thick, preferably from 10 to 100 nm thick, especially from 40 to 60 nm thick, but reflector layers of greater thickness, for example 1 mm thick or even more, are also possible.

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Materials suitable for the covering layer include chiefly plastics, which are applied in a thin layer to the reflector layer either directly or with the aid of adhesion promoters. It is advantageous to select mechanically and thermally stable plastics having good surface properties, which can be modified further, for example written on. The plastics may be thermosetting plastics and thermoplastic plastics. Directly applied covering layers are preferably radiation-cured (e.g. using UV radiation) coatings, which are particularly simple and economical to produce. A wide variety of radiationcurable materials are known. Examples of radiation-curable monomers and oligomers are acrylates and methacrylates of diols, triols and tetrols, polyimides of aromatic tetracarboxylic acids and aromatic diamines having C₁-C₄alkyl groups in at least two ortho-positions of the amino groups, and oligomers with dialkylmaleinimidyl groups, e.g. dimethylmaleinimidyl groups. For covering layers that are applied using adhesion promoters it is preferable to use the same materials as those used for the substrate layer, especially polycarbonates. The adhesion promoters used are preferably likewise radiation-curable monomers and oligomers. Instead of the covering layer applied using an adhesion promoter there may also be used a second substrate comprising a recording and reflector layer, so that the recording medium is

playable on both sides. Preference is given to a symmetrical structure, the two parts being joined together at the reflector side by an adhesion promoter directly or by way of an intermediate layer.

In such a structure, the optical properties of the covering layer, or the covering materials, are essentially unimportant *per se* provided that, where applicable, curing thereof e.g. by UV radiation is achieved. The function of the covering layer is to ensure the mechanical strength of the recording medium as a whole and, if necessary, the mechanical strength of thin reflector layers. If the recording medium is sufficiently robust, for example when a thick reflector layer is present, it is even possible to dispense with the covering layer altogether. The thickness of the covering layer depends upon the thickness of the recording medium as a whole, which should preferably be a maximum of about 2 mm thick. The covering layer is preferably from 10 µm to 1 mm thick.

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The recording media according to the invention may also have additional layers, for example interference layers or barrier layers. It is also possible to construct recording media having a plurality of (for example from two to ten) recording layers. The structure and the use of such materials are known to the person skilled in the art. Where present, interference layers are preferably arranged between the recording layer and the reflecting layer and/or between the recording layer and the substrate and consist of a dielectric material, for example as described in EP-A-0 353 393 of TiO₂, Si₃N₄, ZnS or silicone resins.

The recording media according to the invention can be produced by processes known *per se*, it being possible for various methods of coating to be employed depending upon the materials used and their function.

Suitable coating methods are, for example, immersion, pouring, brush-coating, blade-application and spin-coating, as well as vapour-deposition methods carried out under a high vacuum. When, for example, pouring methods are used, solutions in organic solvents are generally employed. When solvents are employed, care should

- 19 -

be taken that the supports used are insensitive to those solvents. Suitable coating methods and solvents are described, for example, in EP-A-0 401 791.

The recording layer is applied preferably by the application of a dye solution by spin-coating, solvents that have proved satisfactory being especially alcohols, e.g. 2-methoxyethanol, isopropanol or n-butanol, hydroxyketones, for example diacetone alcohol or 3-hydroxy-3-methyl-2-butanone, hydroxy esters, for example lactic acid methyl ester or isobutyric acid methyl ester, or preferably fluorinated alcohols, for example 2,2,2-trifluoroethanol or 2,2,3,3-tetrafluoro-1-propanol, and mixtures thereof. Further suitable solvents are disclosed, for example, in EP-A-0 483 387.

The application of the metallic reflector layer is preferably effected by sputtering or by vapour-deposition in vacuo. Such techniques are known and are described in specialist literature (e.g. J.L. Vossen and W. Kern, "Thin Film Processes", Academic Press, 1978). The operation can advantageously be carried out continuously and achieves good reflectivity and a high degree of adhesiveness of the metallic reflector layer.

Recording is carried out in accordance with known methods by writing pits (marks) of fixed or variable length by means of a modulated, focussed laser beam guided at a constant or variable speed over the surface of the recording layer. Readout of information is carried out according to methods known *per se* by registering the change in reflection using laser radiation, for example as described in "CD-Player und R-DAT Recorder" (Claus Biaesch-Wiepke, Vogel Buchverlag, Würzburg 1992). The person skilled in the art will be familiar with the requirements.

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The information-containing medium according to the invention is especially an optical information material of the WORM type. It can be used, for example, analogously to CD-R (compact disc - recordable) or DVD-R (digital video disc - recordable) in computers, and also as storage material for identification and security cards or for the production of diffractive optical elements, for example holograms.

Alternatively, however, there are also recording media which differ substantially from CD-R and DVD-R and in which recording and playback take place not through the substrate but through the covering layer ("in-groove recording"). Accordingly the respective roles of the covering layer and the substrate, especially the geometry and the optical properties, are reversed in comparison with the structure described above. Analogous concepts are described a number of times in Proceedings SPIE-Int. Soc. Opt. Eng. 1999, 3864 for digital video recordings in conjunction with a blue GaN laser diode. For such recording media, which are especially suitable for a high storage density and have correspondingly small marks ("pits"), precise focussing is important, so that the manufacturing process, while essentially analogous, is considerably more awkward.

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The compounds of formula (I) according to the invention, however, also meet the increased demands of an inverse layer structure surprisingly well. Preference is therefore given to an inverse layer structure having the layer sequence substrate, reflector layer, recording layer and covering layer. The recording layer is therefore located between the reflector layer and the covering layer. A thin covering layer approximately from 50 to 400 μ m in thickness is especially advantageous (typically 100 μ m at a numerical aperture of 0.85).

The recording and reflector layers in an inverse layer structure have in principle the same functions as indicated above. As with the groove geometry, they therefore usually have dimensions within the ranges indicated above.

The inverse layer structure requires particularly high standards, which the compounds used according to the invention fulfil astonishingly well, for example when the recording layer is applied to the metallic reflector layer and especially when a covering layer is applied to the recording layer, the covering layer being required to provide the recording layer with adequate protection against rubbing, photo-oxidation, fingerprints, moisture and other environmental effects and advantageously having a thickness in the range of from 0.01 to 0.5 mm, preferably in the range of

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from 0.05 to 0.2 mm, especially in the range of from 0.08 to 0.13 mm.

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The covering layer preferably consists of a material that exhibits a transmission of 80% or above at the writing or readout wavelength of the laser. Suitable materials for the covering layer include, for example, those materials mentioned above, but especially polycarbonate (such as Pure Ace® or Panlite®, Teijin Ltd), cellulose triacetate (such as Fujitac®, Fuji Photo Film) or polyethylene terephthalate (such as Lumirror®, Toray Industry), special preference being given to polycarbonate. Especially in the case of directly applied covering layers, radiation-cured coatings, such as those already described above, are advantageous, for example SD 347™ (Dainippon Ink).

The covering layer can be applied directly to the solid recording layer by means of a suitable adhesion promoter. In another embodiment, there is applied to the solid recording layer an additional, thin separating layer of a metallic, crosslinked organometallic or preferably dielectric inorganic material, for example in a thickness of from 0.001 to 10 μm , preferably from 0.005 to 1 μm , especially from 0.01 to 0.1 μm , for example from 0.05 to 0.08 μm in the case of dielectric separating layers and from 0.01 to 0.03 μm in the case of metallic separating layers. Separating layers and corresponding methods are disclosed in WO 02/082438, to which reference is expressly made here. If desired, such coatings can be applied, for example, in the same thickness also between the support material and the metallic reflector layer or between the metallic reflector layer and the optical recording layer. This may be advantageous in certain cases, for example when a silver reflector is used in combination with sulfur-containing additives in the recording layer.

In a special variant, there is applied to the solid recording layer an additional, thin separating layer of a metallic, crosslinked organometallic or dielectric inorganic material, for example in a thickness of from 0.001 to 10 μ m, preferably from 0.005 to 1 μ m, especially from 0.01 to 0.1 μ m. On account of their high reflectivity, metallic separating layers should advantageously be a maximum of 0.03 μ m thick.

Separating layers and corresponding methods are disclosed in WO 02/082438, to which reference is expressly made here.

Some of the compounds used according to the invention are known, especially from J. Org. Chem. <u>67</u>/16, 5753-5772 [2002].

5 It is also possible, however, to prepare analogously to the known compounds new compounds that can be used in accordance with the invention in optical recording media.

The invention therefore relates also to compounds of formula (I), with the exception of the already known compounds of formula $M_2(\mathbb{Z}_1)_2$, wherein:

10 • M_2 is Co(II), Cu(II), Hg(II), Ni(II), Pd(II) or Zn(II) and Z_1 is

 \circ M_2 is Co(II), Cu(II), Ni(II), Pd(II) or Zn(II) and Z_1 is

$$\begin{array}{c|c} & & & & & & & & & & & & & & & \\ & & & & & & & & & & & & & \\ & & & & & & & & & & & \\ & & & & & & & & & & \\ & & & & & & & & & \\ & & & & & & & & & \\ & & & & & & & & \\ & & & & & & & & \\ & & & & & & & \\ & & & & & & & \\ & & & & & & & \\ & & & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & \\ & & & \\ & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & \\ & & \\ & \\ & & \\ & \\ & & \\$$

• M₂ is Co(II), Cu(II), Ni(II) or Zn(II) and Z₁ is

• M₂ is Co(II), Cu(II) or Zn(II) and Z₁ is

$$\begin{array}{c|c} H_3C & CH_3 \\ N & N & N \end{array} \text{ or } \begin{array}{c} H_3C & CH_3 \\ N & N & N \end{array}$$

• M₂ is Cu(II) or Zn(II) and Z₁ is

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$$\stackrel{\text{CH}_3}{\underset{\text{N}}{\bigvee}}$$
 , $\stackrel{\text{S}}{\underset{\text{COOEt}}{\bigvee}}$ or $\stackrel{\text{S}}{\underset{\text{N}}{\bigvee}}$;

• M_2 is Co(II) or Cu(II) and Z_1 is O_2N NO_2 ;

• M_2 is Pd(II) or Zn(II) and Z_1 is

• M_2 is Cu(II) and Z_1 is N N or N ; or

•
$$M_2$$
 is $Zn(II)$ and Z_1 is N or N

Reference is made especially to compounds of formulae

- 25 -

$$C_{1} = \begin{pmatrix} C_{1} & C_$$

Cu, Co, Ni or Pd and Z_1 is a radical of the following compounds:

$$\begin{array}{c} \text{Me}_{2}\text{NSO}_{2} \\ \text{Me}_{2}\text{NSO}_{2} \\ \text{NH}_{2} \\ \text{NH}_{2} \\ \text{SO}_{2} \\ \text{NH}_{2} \\ \text{N$$

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Especially interesting properties are exhibited by the preferred compounds of

formulae
$$R_1$$
 R_2 G_2 R_3 (III) and R_1 R_2 G_2 R_4 R_3 (III) and R_1 R_2 G_2 G_3 R_4

also mixtures of compounds of formula (II) and/or (III), wherein especially G_1 and G_2 are the preferred heterocycles disclosed above and at the same time or independently thereof M_1 is a preferred transition metal. A_3 in G_1 and G_2 can be especially $N(R_{12})$, O, S or, especially in formula (III), $C(C_1-C_5alkyl)_2$.

Special preference is given to compounds of formula

$$R_{32}$$
 A_1 Q_1 A_3 R_{34} R_{35} R_{35} R_{35} R_{36} R_{39} R_{36} R_{36} R_{36} R_{36} R_{36} R_{36}

dently of A₃, has the same definition and the same preferred meanings as A₃.

10 Very special preference is given to compounds of formula

Both in formula (IV) and in formula (V), R_{32} , R_{33} , R_{34} , R_{35} , R_{36} , R_{37} , R_{38} and R_{39} are preferably H, C_1 - C_4 alkyl, COO- C_1 - C_4 alkyl, CN, NO_2 , CHO, COC_1 - C_4 alkyl, phenyl, $CH[-O-C_2-C_3$ alkylene-O-], $C(C_1-C_4$ alkyl)[- $O-C_2-C_3$ alkylene-O-], $CH=C(CN)_2$, $C(CN)=C(CN)_2$ or $C(C_1-C_4$ alkyl)= $C(CN)_2$, especially H, CH_3 , C_2H_5 , $COOCH_3$,

- 39 -

COOC₂H₅, CN, NO₂ or CHO.

Compounds of formula (IV) are, for example, the following:

Nº	Formula	A ₁ =A ₂	A ₃ =A ₄	Q ₁ =Q ₂	R ₃₂ =R ₃₆	R ₃₃ =R ₃₇	R ₃₄ =R ₃₈	R ₃₅ =R ₃₉	M ₁
D1	(IV)	NCH₃	0	N	Н	Н	Н	Н	Co ²⁺
D2	(IV)	NCH ₂ CH ₃	0	N	CH ₃	Н	CH₃	Н	Co ²⁺
D3	(IV)	NCH ₂ CH ₃	0	N	CH ₃	Н	Н	Н	Co ²⁺
D4	(IV)	s	0	N	NO_2	Н	Н	Н	Co ²⁺
D5	(IV)	s	0	N	NO ₂	Н	CH ₃	Н	Co ²⁺
D6	(IV)	NCH₃	NCH₃	N	NO_2	Н	NO_2	Н	Co ²⁺
D7	(IV)	NCH ₂ CH ₃	NCH ₂ CH ₃	N	CN	Н	CN	Н	Co ²⁺
D8	(IV)	s	NCH ₂ CH ₃	N	Н	Н	Н	Н	Co ²⁺
D9	(IV)	0	0	СН	NO ₂	Н	NO_2	Н	Co ²⁺
D10	(IV)	0	0	СН	CN	Н	CN	Н	Co ²⁺
D11	(IV)	0	0	СН	SCH₃	Н	SCH₃	H	Co ²⁺
D12	(IV)	s	s	N	t-C ₄ H ₉	Н	t-C ₄ H ₉	Н	Co ²⁺
D13	(IV)	s	s	N	СНО	Н	СНО	Н	Co ²⁺
D14	(IV)	s	s	N	Н	i-C ₃ H ₇	Н	i-C ₃ H ₇	Co ²⁺
D15	(IV)	s	s	N	CHC(CN) ₂	Н	CHC(CN) ₂	Н	Co ²⁺
D16	(IV)	NCH₃	0	N	Н	Н	Н	Н	Cu ²⁺
D17	(IV)	NCH ₂ CH ₃	0	N	CH₃	Н	CH₃	Н	Cu ²⁺
D18	(IV)	NCH ₂ CH ₃	0	N	CH₃	Н	Н	Н	Ni ²⁺
D19	(IV)	s	0	N	NO ₂	Н	Н	Н	Cu ²⁺
D20	(IV)	s	0	N	NO ₂	Н	СН₃	Н	Cu ²⁺
D21	(IV)	NCH ₃	NCH ₃	N	NO ₂	Н	NO ₂	Н	Ni ²⁺

- 40 -

Nº	Formula	A ₁ =A ₂	A ₃ =A ₄	$Q_1=Q_2$	R ₃₂ =R ₃₆	R ₃₃ =R ₃₇	R ₃₄ =R ₃₈	R ₃₅ =R ₃₉	M ₁
D22	(IV)	NCH ₂ CH ₃	NCH ₂ CH ₃	N	CN	Н	CN	Н	Cu ²⁺
D23	(IV)	s	NCH ₂ CH ₃	N	Н	Н	Н	Н	Cu ²⁺
D24	(IV)	0	0	СН	NO_2	Н	NO_2	Н	Ni ²⁺
D25	(IV)	0	0	СН	CN	Н	CN	Н	Cu ²⁺
D26	(IV)	0	0	СН	SCH₃	Н	SCH₃	Н	Cu ²⁺
D27	(IV)	s	s	N	t-C ₄ H ₉	Н	t-C₄H ₉	Н	Ni ²⁺
D28	(IV)	s	s	N	CHO	Н	CHO	Н	Cu²⁺
D29	(IV)	s	s	N	Н	i-C₃H ₇	Н	i-C ₃ H ₇	Cu ²⁺
D30	(IV)	s	s	N	CHC(CN) ₂	Н	CHC(CN) ₂	Н	Ni ²⁺

Compounds of formula (V) are, for example, the following:

Ν°	Formula	R ₃₂ =R ₃₆	R ₃₃ =R ₃₇	R ₃₄ =R ₃₈	R ₃₅ =R ₃₉	M_1
D31	(V)	Н	Н	Н	Н	Co ²⁺
D32	(V)	CH ₃	Н	CH ₃	Н	Co ²⁺
D33	(V)	CH ₃	Н	Н	Н	Co ²⁺
D34	(V)	Н	CH ₃	Н	CH₃	Co ²⁺
D35	(V)	Н	Н	Н	CH₃	Co ²⁺
D36	(V)	CH ₂ CH ₃	Н	CH ₂ CH ₃	Н	Co ²⁺
D37	(V)	CH₂CH₃	Н	Н	Н	Co ²⁺
D38	(V)	n-C ₃ H ₇	Н	n-C₃H ₇	Н	Co ²⁺
D39	(V)	n-C ₃ H ₇	Н	Н	Н	Co ²⁺
D40	(V)	i-C₃H ₇	Н	i-C ₃ H ₇	Н	Co ²⁺
D41	(V)	i-C ₃ H ₇	Н	Ħ	Н	Co ²⁺

- 41 -

Ν°	Formula	R ₃₂ =R ₃₆	R ₃₃ =R ₃₇	R ₃₄ =R ₃₈	R ₃₅ =R ₃₉	M ₁
D42	(V)	n-C₄H ₉	Н	n-C ₄ H ₉	Н	Co ²⁺
D43	(V)	n-C ₄ H ₉	Н	Н	Н	Co ²⁺
D44	(V)	i-C ₃ H ₇	CH ₃	i-C ₃ H ₇	CH ₃	Co ²⁺
D45	(V)	Н	Н	i-C ₃ H ₇	CH ₃	Co ²⁺
D46	(V)	Н	i-C ₄ H ₉	Н	i-C ₄ H ₉	Co ²⁺
D47	(V)	Н	i-C₄H ₉	Н	Н	Co ²⁺
D48	(V)	COOCH ₂ CH ₃	CH ₃	COOCH ₂ CH ₃	CH ₃	Co ²⁺
D49	(V)	COOCH ₂ CH ₃	CH ₃	Н	Н	Co ²⁺
D50	(V)	Н	COOCH ₂ CH ₃	Н	Н	Co ²⁺
D51	(V)	Н	COOCH ₂ CH ₃	Н	COOCH ₂ CH ₃	Co ²⁺
D52	(V)	CH=C(CN) ₂	Н	CH=C(CN) ₂	Н	Co ²⁺
D53	(V)	NO ₂	Н	NO_2	Н	Co ²⁺
D54	(V)	Н	Н	Н	Н	Cu ²⁺
D55	(∀)	CH₃	Н	CH ₃	н	Cu ²⁺
D56	(V)	CH ₃	Н	Н	Н	Cu ²⁺
D57	(V)	Н	CH ₃	Н	CH ₃	Cu ²⁺
D58	(V)	Н	Н	Н	CH ₃	Cu ²⁺
D59	(V)	CH₂CH₃	Н	CH ₂ CH ₃	Н	Cu ²⁺
D60	(V)	CH₂CH₃	Н	Н	Н	Cu ²⁺
D61	(V)	n-C ₃ H ₇	Н	n-C ₃ H ₇	Н	Cu ²⁺
D62	(V)	n-C₃H ₇	Н	Н	Н	Cu ²⁺
D63	(V)	i-C ₃ H ₇	Н	i-C ₃ H ₇	Н	Cu ²⁺
D64	(V)	i-C ₃ H ₇	Н	Н	Н	Cu ²⁺
D65	(V)	n-C₄H ₉	Н	n-C₄H ₉	Н	Cu ²⁺

- 42 -

Ν°	Formula	R ₃₂ =R ₃₆	R ₃₃ =R ₃₇	R ₃₄ =R ₃₈	R ₃₅ =R ₃₉	M ₁
D66	(V)	n-C ₄ H ₉	Н	Н	Н	Cu ²⁺
D67	(V)	i-C ₃ H ₇	СН₃	i-C ₃ H ₇	CH₃	Cu ²⁺
D68	(V)	Н	Н	i-C₃H ₇	CH₃	Cu ²⁺
D69	(V)	Н	i-C₄H ₉	Н	i-C ₄ H ₉	Cu ²⁺
D70	(V)	Н	i-C ₄ H ₉	Н	Н	Cu ²⁺
D71	(V)	COOCH ₂ CH ₃	CH ₃	COOCH ₂ CH ₃	CH ₃	Cu ²⁺
D72	(V)	COOCH ₂ CH ₃	CH ₃	Н	Н	Cu²⁺
D73	(V)	Н	COOCH ₂ CH ₃	Н	Н	Cu ²⁺
D74	(V)	Н	COOCH ₂ CH ₃	Н	COOCH ₂ CH ₃	Cu ²⁺
D75	(V)	CH=C(CN) ₂	Н	CH=C(CN) ₂	Н	Cu ²⁺
D76	(V)	NO_2	Н	NO_2	Н	Cu ²⁺
D77	(V)	Н	Н	Н	Н	Ni ²⁺
D78	(V)	CH ₃	Н	CH ₃	Н	Ni ²⁺
D79	(V)	CH ₃	Н	Н	Н	Ni ²⁺
D80	(V)	Н	CH ₃	Н	CH₃	Ni ²⁺
D81	(V)	Н	Н	н	CH₃	Ni ²⁺
D82	(V)	CH ₂ CH ₃	Н	CH ₂ CH ₃	Н	Ni ²⁺
D83	(V)	CH ₂ CH ₃	Н	Н	Н	Ni ²⁺
D84	(V)	n-C ₃ H ₇	Н	n-C ₃ H ₇	Н	Ni ²⁺
D85	(V)	n-C ₃ H ₇	Н	Н	Н	Ni ²⁺
D86	(V)	i-C ₃ H ₇	Н	i-C₃H ₇	Н	Ni ²⁺
D87	(V)	i-C ₃ H ₇	Н	Н	Н	Ni ²⁺
D88	(V)	n-C₄H ₉	Н	n-C₄H ₉	Н	Ni ²⁺
D89	(V)	n-C₄H ₉	Н	Н	Н	Ni ²⁺

- 43 -

Ν°	Formula	R ₃₂ =R ₃₆	R ₃₃ =R ₃₇	R ₃₄ =R ₃₈	R ₃₅ =R ₃₉	M ₁
D90	(V)	i-C₃H ₇	CH ₃	i-C ₃ H ₇	CH₃	Ni ²⁺
D91	(V)	Н	Н	i-C₃H ₇	CH ₃	Ni ²⁺
D92	(V)	Н	i-C₄H ₉	Н	i-C ₄ H ₉	Ni ²⁺
D93	(V)	н	i-C ₄ H ₉	Н	Н	Ni^{2+}
D94	(V)	COOCH ₂ CH ₃	CH ₃	COOCH ₂ CH ₃	CH ₃	Ni ²⁺
D95	(V)	COOCH ₂ CH ₃	CH ₃	Н	Н	Ni ²⁺
D96	(V)	Н	COOCH ₂ CH ₃	Н	Н	Ni ²⁺
D97	(V)	Н	COOCH ₂ CH ₃	Н	COOCH ₂ CH ₃	Ni ²⁺
D98	(V)	CH=C(CN) ₂	Н	CH=C(CN) ₂	Н	Ni ²⁺
D99	(V)	NO_2	Н	NO_2	Н	Ni ²⁺

Instead of pure compounds it is also possible to use mixtures thereof, for example the following mixtures:

N_{o}		%		%		%	%	%
М1	D54	80	D77	20				
M2	D32	5	D54	80	D77	15		
МЗ	D54	80	D55	10	D78	10		
M4	D54	80	D56	15	D79	5		
M5	D54	80	D55	10	D56	10		
M6	D54	80	D56	20				
M7	D54	80	D56	15	D79	5		
M8	D54	90	D57	10				
M9	D54	80	D57	10	D81	10		
M10	D54	80	D58	20				

- 44 -

Ν°		%		%		%		%		%
M11	D54	80	D57	10	D58	10				
M12	D54	65	D57	10	D58	5	D77	15	D81	5
M13	D54	90	D59	10						
M14	D54	80	D60	20						
M15	D54	70	D59	5	D60	10	D76	5	D82	5
M16	D56	90	D61	10						
M17	D56	90	D62	10						
M18	D54	90	D68	10						
M19	D54	90	D71	10						
M20	D54	75	D72	15	D76	5	D95	5		
M21	D54	70	D73	20	D76	5	D96	5		
M22	D54	80	D74	20						
M23	D54	80	D55	5	D56	5	D57	5	D76	5
M24	M5	50	M14	30	D58	5	D76	5	D77	10

Instead of preparing mixtures by mixing together the components, it is favourably possible to prepare mixtures by mixed synthesis, the metals being added in any desired order in succession or preferably simultaneously to a pre-prepared mixture of the ligands, or conversely the ligands being added in any desired order in succession or preferably all of them simultaneously to a pre-prepared mixture of the metals. The mixtures prepared by mixed synthesis generally have somewhat better solubility than physical mixtures, possibly because of their asymmetric components.

In addition to comprising one or more compounds of formula (I) and optionally

customary additives, the optical recording media according to the invention may also
comprise other chromophores, preferably metal-free chromophores. Other
chromophores may, if desired, be added in an amount of from 1 to 200 % by weight,

15

based on the total of the compounds of formula (I). The amount of other chromophores is preferably from 5 to 100 % by weight, especially from 10 to 50 % by weight, based on the total of the compounds of formula (I). Chromophores can be dyes or UV absorbers, preferably having an absorption maximum of from 350 to 400 nm or at from 600 to 700 nm, for example around 380 or 630 nm.

Especially preferred additional metal-free chromophores are cyanines, azacyanines, merocyanines and oxonols and also rhodamines, for example those disclosed in WO 04/006878, WO 02/082438 or EP-A-1 083 555, and also

wherein R_{40} is C_1 - C_2 4alkyl or C_2 - C_2 4alkenyl, each of which can be unsubstituted or substituted, and R_{41} is any substituent. R_{40} may be, for example, methyl, ethyl, vinyl, allyl, isopropyl, n-butyl, 2-isopropyloxy-ethyl, n-pentyl, 3-methyl-butyl, 3,3-dimethyl-butyl, 2-ethyl-hexyl, 2-cyano-ethyl, furan-2-yl-methyl or 2-hydroxy-methyl; R_{41} is, for example, C_6 - C_{10} aryl, C_1 - C_2 4alkyl or C_2 - C_2 4alkenyl.

Purely illustrative examples of such chromophores are:

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The following Examples illustrate the invention but do not limit the scope thereof (unless otherwise indicated, "%" always refers to % by weight):

Example 1: 1.0 g of the compound of formula

the form of a dichloromethane solution to glass. The solid layer is irradiated for 90 hours with xenon light according to ISO-105-B02 (Atlas Ci-35 Weather-O-meter, 15 kJ/cm²). The light stability is excellent (see Example 7).

5 Example 2: On the solid layer according to Example 1, marks are written into the recording layer using a pulsed dye laser (15 ns pulse length) at a wavelength of 405 nm at an energy density of 0.8 kJ/m². The written sites exhibit a resulting change in reflectivity.

Example 3: 0.5 g of the compound according to Example 1 is dissolved in 99.5 g of dioxane and applied by means of spin-coating to a silicon wafer. The colourless solid layer is measured using a spectral ellipsometer (Sopra). At a wavelength of 405 nm a refractive index of 2.52 is determined.

Example 4: 1.0 g of the compound of formula

a
$$t-C_4H_9$$
 is $t-C_4H_9$ is $t-C_4H_9$ is

dissolved in 99 g of methylcyclohexane and filtered through a 0.2 μm Teflon filter.

The dye solution is then applied by rotation at 250 rev/min to a 1.2 mm thick, flat polycarbonate plate (diameter 120 mm). The rotational speed is then increased to 1200 rev/min, so that the excess solution is spun off, and a uniform solid layer is formed. After drying, the solid layer has an absorption of 0.61 at 382 nm. Using an optical measuring system (ETA-RT, STEAG ETA-Optik), the layer thickness and the

complex refractive index are determined. At 405 nm the dye layer has a layer thickness of 56 nm, a refractive index n of 1.95 and an extinction coefficient k of 0.090.

Example 5:

10

5 Synthesis of the ligand

19.4 ml of a 55 % aqueous chloracetaldehyde solution are added to a suspension of 10.2 g of dithiobiuret in 45 ml of ethanol. The reaction mixture is heated at 75°C for 2 hours, and then poured into 150 ml of water. After the addition of 200 ml of an aqueous sodium acetate solution (4.6N), the precipitate is filtered off, washed with water and dried at 50°C/1.5 · 10³ Pa, yielding 8.8 g of crude product, and after recrystallisation from ethanol 6.7 g of pure product of formula (S)NH NS (m.p. 212°C).

Synthesis of the complex

0.5N aqueous copper(II) acetate solution is added to a solution of 458 mg of the
 resulting ligand in 30 ml of ethanol until precipitation, which begins immediately, is
 complete. After filtration, the product is washed with ethanol and diethyl ether, and

then dried at 70°C/1.5 · 103 Pa. 390 mg of pure product of formula

Cu N N S

(decomp. 264°C) are obtained.

Example 6: 1.0 g of the complex according to Example 5 is dissolved in 99 g of 2,2,3,3-tetrafluoro-1-propanol and filtered through a 0.2 μm Teflon filter. The dye solution is then applied by rotation at 250 rev/min to a 1.2 mm thick, flat polycarbonate plate (diameter 120 mm); the rotational speed is then increased to 1500 rev/min, so that the excess solution is spun off and a uniform solid layer is

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formed. After drying, the solid layer has an absorption of 0.35 at 356 nm. Using an optical measuring system (ETA-RT, STEAG ETA-Optik), the layer thickness and the complex refractive index are determined. At 405 nm the dye layer has a layer thickness of 18 nm, a refractive index n of 2.25 and an extinction coefficient k of 0.031.

Examples 7-38: The procedure is analogous to Example 6, but instead of the complex of Example 5 the following ligands and metal cations are used:

Metal	Ligand (2×)	λ _{max} [nm]	Solvent	n	k
Cu²⁺		370	CH₃CN (+HCl)	2.52	0.47
Cu ²⁺	H_3C N N N CH_3	383	CH ₂ Cl ₂	2.30	0.185
Ni²⁺	H ₃ CO-N-N-S-OCH ₃	370	CH ₂ Cl ₂	2.23	0.160
Cu ²⁺	H ₃ CO-NNNS-OCH ₃	390	CH ₂ Cl ₂	2.22	0.266
Cu ²⁺	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	377	CH ₂ Cl ₂	2.21	0.244
Co ²⁺	H_3C N N N N CH_3	370	CH ₂ Cl ₂	2.20	0.137
Co ²⁺	H ₃ CO-NNNS-OCH ₃	376	CH ₂ Cl ₂	2.19	0.179

Metal	Ligand (2×)	λ _{max} [nm]	Solvent	n	k
Ni ²⁺	H_3C N N N CH_3	361	CH ₂ Cl ₂	2.17	0.108
Co ²⁺	$H_5C_2SO_2$ $SO_2C_2H_5$	370	CH ₂ Cl ₂	2.08	0.158
Ni ²⁺	SYN S N N	361	CH ₂ Cl ₂	2.07	0.097
Cu ²⁺	SYNTS N N	384	CH ₂ Cl ₂	2.00	0.092
Co ²⁺	H_3C CH_3	351	CH ₂ Cl ₂	1.98	0.100
Co ²⁺	- STNTS	370	CH ₂ Cl ₂	1.94	0.083
Ni ²⁺	H_3C CH_3	350	CH ₂ Cl ₂	1.93	0.083
Co ²⁺	O H O O O O O O O O O O O O O O O O O O	367	CH ₂ Cl ₂	1.83	0.103

Metal	Ligand (2×)	λ _{max} [nm]	Solvent	n	k
Ni ²⁺	$H_5C_2SO_2$ $H_5C_2SO_2$ H_5	368	CH ₂ Cl ₂	1.74	0.119
Cu ²⁺	S N S N N N	369	CH ₂ Cl ₂		
Ni ²⁺	S N S N N	350	CH ₂ Cl ₂		
Co ²⁺	S N S H ₃ C	348	CH ₂ Cl ₂		
Ni ²⁺	O C O O O O O O O O O O O O O O O O O O	356	CH₃CN		
Ni ²⁺	N N N	357	CH ₂ Cl ₂		
Co ²⁺	O Y C Y O	364	CH ₂ Cl ₂		
Co ²⁺	S N S	370	CH₃CN (+HCl)		

Metal	Ligand (2×)	λ _{max} [nm]	Solvent	n	k
Ni ²⁺	S N S	370	CH₃CN (+HCl)		
Cu ²⁺	O C V	374	CH ₂ Cl ₂		
Ni ²⁺	CH ₃	374	CH ₂ Cl ₂		
Co ²⁺	CH ₃	376	CH₃CN		
Cu ²⁺	CH ₃ O	387	CH ₂ Cl ₂		
Cu ²⁺	H ₃ C CH ₃				
Ni ²⁺	H_3C N N S CH_3				
Co ²⁺	$H_3C - S + N + S + CH_3$	350	CH ₂ Cl ₂		
Cu ²⁺	H_3C N N S CH_3	358	CH ₂ Cl ₂		

Examples 39 - 62: The procedure is analogous to Example 6, but instead of the complex of Example 5 the mixtures M1 to M24 are used.

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Examples 63 – 86: The procedure is analogous to Example 6, but instead of the complex of Example 5 there are used mixtures having the same proportions of metal and ligand as mixtures M1 to M24 but the complexes are prepared by mixed synthesis (variant of the simultaneous addition of the metal mixture to the ligand mixture). The results are similar to those of Examples 39 – 62, but have surprisingly better solubility and solution stability.

<u>Examples 87 – 94</u>: The procedure is analogous to Example 6, but instead of the complex of Example 5 there are used the following mixtures of compounds of formula (I) with cyanines and merocyanines:

- 55 -

It will be understood that it is also possible to combine mixtures of those cyanines, merocyanines and/or also other chromophores with complexes of formula (I) or with mixtures of complexes of formula (I), the results achieved generally being very good.

What is claimed is:

1. An optical recording medium comprising a substrate, a recording layer and optionally one or more reflecting layers, wherein the recording layer comprises a

compound of formula
$$R_1$$
 R_2 R_3 R_4 R_3 R_4 R_3 (I) or a tautomer thereof, wherein

5 G₁ and G₂ are each independently of the other

 A_1 and A_2 are each independently of the other N(R₁₂), O, S or Se and A_3 is C(C₁-C₅alkyl)₂, C(C₄-C₅alkylene), N(R₁₂), O, S, Se, N=C(R₁₃) or unsubstituted or R₁₄-substituted CH=CH;

10 M₁ is a transition metal of groups IX to XII, preferably Co, Cu, Ni, Pd or Zn, especially Co, Cu or Ni;

 Q_1 and Q_2 are each independently of the other $C(R_{15})$, N or P;

R₁, R₂, R₃, R₄, R₅, R₆, R₇, R₈ and R₁₄ are each independently of the others hydrogen, R₁₈, or C₆-C₁₂aryl, C₄-C₁₂heteroaryl, C₇-C₁₂aralkyl or C₅-C₁₂heteroaralkyl each unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₈; or

 R_1 and R_2 , R_3 and R_4 , R_5 and R_6 , R_5 and R_{13} and/or R_5 and R_{14} , together in pairs, are C_3 - C_6 alkylene or C_3 - C_6 alkenylene, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R_{17} and may be

uninterrupted or interrupted by O, S or N(R₁₂), or 1,4-buta-1,3-dienylene,



25

or , each of which is unsubstituted or substituted by one or more, where

applicable identical or different, radicals R₁₈ and in which 1 or 2 carbon atoms may have been replaced by nitrogen;

R₉, R₁₂ and R₁₃ are each independently of the others C₁-C₂₄alkyl, C₃-C₂₄cycloalkyl, C2-C24alkenyl, C3-C24cycloalkenyl, C1-C4alkyl-[O-C1-C4alkylene] or C1-C4alkyl-[NH-C₁-C₄alkylene]_m, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₇; or C₆-C₁₂aryl, C₄-C₁₂heteroaryl, C7-C12aralkyl or C5-C12heteroaralkyl, each of which is unsubstituted or substituted by 10 one or more, where applicable identical or different, radicals R₁₈;

R₁₀, R₁₁ and R₁₈ are each independently of the others halogen, nitro, cyano, thiocyanato, hydroxy, O-R₁₉, O-CO-R₁₉, S-R₁₉, CHO, COR₂₀, CHOR₁₉OR₂₃, CR₂₀OR₁₉OR₂₃, R₁₆, N=N-R₁₆, N=CR₁₉R₂₀, N=CR₂₁R₂₂, C(R₁₅)=NR₁₉, $C(R_{15})=NR_{21}$, $C(R_{15})=CR_{21}R_{22}$, NH_2 , NH_2R_{19} , $NR_{19}R_{20}$, NH_3 , NH_2R_{19} , $NHR_{19}R_{20}$,

NR₁₉R₂₀R₂₃⁺, CONH₂, CONHR₁₉, CONR₁₉R₂₀, SO₂R₁₉, SO₂NH₂, SO₂NHR₁₉, 15 SO₂NR₁₉R₂₀, COOH, COOR₁₉, OCOOR₁₉, NHCOR₁₉, NR₁₉COR₂₃, NHCOOR₁₉, NR₁₉COOR₂₃, ureido, NR₁₉-CO-NHR₂₃, B(OH)₂, B(OH)(OR₁₉), B(OR₁₉)OR₂₃, phosphato, PR₁₉R₂₃, POR₁₉OR₂₃, P(=O)OR₁₉OR₂₃, OPR₁₉R₂₃, OPR₁₉OR₂₃, OP(=O)R₁₉OR₂₃, OP(=O)OR₁₉OR₂₃, OPO₃R₁₉, sulfato, sulfo, or C₁-C₁₂alkyl,

20 C₃-C₁₂cycloalkyl, C₁-C₁₂alkylthio, C₃-C₁₂cycloalkylthio, C₁-C₁₂alkoxy or C₃-C₁₂cycloalkoxy each unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₇;

R₁₅ is hydrogen, cyano, hydroxy, C₁-C₁₂alkoxy, C₃-C₁₂cycloalkoxy, C₁-C₁₂alkylthio, C₃-C₁₂cycloalkylthio, amino, NHR₂₄, NR₂₅R₂₆, R₂₇, halogen, nitro, formyl, N=N-R₂₇, C(R₁₄)=CR₂₁R₂₂, C(R₁₄)=NR₁₉, COO-R₂₅, carboxy, carbamoyl, CONH-R₂₅,

CONR₂₅R₂₆, N=CR₁₉R₂₀, or C₁-C₁₂alkyl, C₃-C₁₂cycloalkyl, C₂-C₁₂alkenyl or C₃-C₁₂cycloalkenyl each unsubstituted or substituted by one or more, where applicable identical or different, halogen, hydroxy, C₁-C₁₂alkoxy or C₃-C₁₂cycloalkoxy radicals:

- 5 R₁₆ is C₆-C₁₂aryl, C₄-C₁₂heteroaryl, C₇-C₁₂aralkyl or C₅-C₁₂heteroaralkyl, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R₂₈;
- R₁₇ is halogen, hydroxy, O-R₂₅, O-CO-R₂₅, S-R₂₅, NH₂, NH-R₂₅, NR₂₅R₂₆, NH₃⁺, NH₂R₂₅⁺, NH₂R₂₆⁺, NR₂₄R₂₅R₂₆⁺, NR₂₅-CO-R₂₄, NR₂₅COOR₂₄, cyano, formyl,

 10 COO-R₂₅, carboxy, carbamoyl, CONH-R₂₅, CONR₂₅R₂₆, ureido, NH-CO-NHR₂₄, NR₂₅-CO-NHR₂₄, phosphato, PR₂₅R₂₄, POR₂₅OR₂₄, P(=O)OR₂₅OR₂₄, OPR₂₅R₂₄, OPR₂₅OR₂₄, OPR₂₅OR₂₄, OPR₂₅OR₂₄, OPR₂₅OR₂₄, SO₂R₂₅, sulfato, sulfo, R₂₇, N=N-R₂₇, or C₁-C₁₂alkoxy or C₁-C₁₂cycloalkoxy each unsubstituted or mono- or poly-substituted by halogen;
- R₁₉, R₂₀ and R₂₃ are each independently of the others R₁₆, or C₁-C₁₂alkyl, C₃-C₁₂cycloalkyl, C₂-C₁₂alkenyl or C₃-C₁₂cycloalkenyl, each of which is unsubstituted or substituted by one or more, where applicable identical or different, halogen, hydroxy, C₁-C₁₂alkoxy or C₃-C₁₂cycloalkoxy radicals; or
- R₁₄ and R₁₉ together, R₁₅ and R₁₈ together and/or R₁₈ and R₂₃ together are

 C₂-C₁₂alkylene, C₃-C₁₂cycloalkylene, C₂-C₁₂alkenylene or C₃-C₁₂cycloalkenylene,
 each of which is unsubstituted or substituted by one or more, where applicable
 identical or different, halogen, hydroxy, C₁-C₁₂alkoxy or C₃-C₁₂cycloalkoxy radicals;
 or
- R₁₉ and R₂₀ together with the common nitrogen are pyrrolidine, piperidine, piperazine or morpholine, each of which is unsubstituted or mono- to tetra-substituted by C₁-C₄alkyl; or carbazole, phenoxazine or phenothiazine, each of which is unsubstituted or substituted by one or more, where applicable identical or different,

radicals R₂₈;

 R_{21} and R_{22} are each independently of the other NR₂₅R₂₆, CN, CONH₂, CONHR₁₉, CONR₁₉R₂₀ or COOR₂₀;

R₂₄, R₂₅ and R₂₆ are each independently of the others C₁-C₁₂alkyl, C₃-C₁₂cycloalkyl,

C₂-C₁₂alkenyl, C₃-C₁₂cycloalkenyl, C₆-C₁₂aryl, C₄-C₁₂heteroaryl, C₇-C₁₂aralkyl or

C₅-C₁₂heteroaralkyl; or

 R_{25} and R_{26} together with the common nitrogen are pyrrolidine, piperidine, piperazine or morpholine, each of which is unsubstituted or mono- to tetra-substituted by C_1 - C_4 alkyl;

10 R₂₇ is C₆-C₁₂aryl, C₄-C₁₂heteroaryl, C₇-C₁₂aralkyl or C₅-C₁₂heteroaralkyl, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₈;

 R_{28} is nitro, SO_2NHR_{25} , $SO_2NR_{25}R_{26}$, or C_1 - C_{12} alkyl, C_3 - C_{12} cycloalkyl, C_1 - C_{12} alkylthio, C_3 - C_{12} cycloalkylthio, C_1 - C_{12} alkoxy or C_3 - C_{12} cycloalkoxy, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R_{17} ; and

m is a number from 1 to 10.

15

2. An optical recording medium according to claim 1, wherein Q₁ and Q₂ are C(R₁₅);

$$G_1$$
 and G_2 are $\stackrel{A_3}{\longleftarrow} R_{18}$; and A_1 , A_2 and A_3 are O, S or N(R₁₂);

20 R₁₂ is C₁-C₂₄alkyl, C₁-C₄alkyl-[O-C₁-C₄alkylene]_m or C₁-C₄alkyl-[NH-C₁-C₄alkylene]_m, each of which is unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₇, or C₆-C₁₂aryl unsubstituted or substituted by one or more, where applicable identical or different, radicals R₁₈;

R₁₅ is hydrogen, cyano, COO-R₂₅ or C₁-C₁₂alkyl;

R₁₇ is halogen, hydroxy, O-R₂₅, cyano, COO-R₂₅ or carboxy; and

 R_{18} is halogen, nitro, cyano, O-R₁₉, CH=C(CN)₂, COOR₁₉, ureido, CONR₂₅R₂₆, SO₂R₂₅, P(=O)OR₁₉OR₂₃ or unsubstituted or substituted C₁-C₁₂alkyl.

5 3. An optical recording medium according to claim 1 or 2, wherein the recording

layer comprises a compound of formula (I) wherein

n
$$R_1$$
 R_2 and/or

$$\begin{array}{c|c} & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & \\ & & & \\ & &$$

- 4. An optical recording medium according to claim 1, 2 or 3, wherein the compound of formula (I) contains branched C₃-C₂₄alkyl or branched C₃-C₂₄alkenyl.
- 5. An optical recording medium according to claim 1, 2, 3 or 4, wherein the recording layer is substantially amorphous.

5

- 6. An optical recording medium according to claim 1, 2, 3, 4 or 5, additionally comprising a covering layer, wherein substrate, reflector layer, recording layer and covering layer are arranged in that order.
- 7. An optical recording medium according to claim 1, 2, 3, 4, 5 or 6, which in addition to comprising a compound of formula (I) comprises a metal-free chromophore.
 - 8. A method of recording or playing back data, wherein the data on an optical recording medium according to claim 1, 2, 3, 4, 5, 6 or 7 are recorded or played back at a wavelength of from 350 to 500 nm.
- 9. A compound of formula (I) according to claim 1, with the proviso that the compound is not a compound of formula $M_2(\mathbb{Z}_1)_2$, wherein:
 - M_2 is Co(II), Cu(II), Hg(II), Ni(II), Pd(II) or Zn(II) and Z_1 is

∘ M₂ is Co(II), Cu(II), Ni(II), Pd(II) or Zn(II) and Z₁ is

15 $NCH_3^+ CF_3SO_3^ NCH_3^+ CF_3SO_3^ NCH_3^+ CF_3SO_3^ NCH_3^+ CF_3SO_3^ NCH_3^+ CF_3SO_3^ NCH_3^+ CF_3SO_3^-$

M₂ is Cu(II), Pd(II) or Zn(II) and Z₁ is

M₂ is Co(II), Cu(II) or Zn(II) and Z₁ is

$$N = N$$
 or
$$N = N$$
 or
$$N = N$$
 or
$$N = N$$

M₂ is Cu(II) or Zn(II) and Z₁ is

• M_2 is Co(II) or Cu(II) and Z_1 is O_2N NO_2

 \circ M₂ is Pd(II) or Zn(II) and Z₁ is

• M₂ is Cu(II) and Z₁ is S Or N N N ; or EtOOC COOEt

•
$$M_2$$
 is $Zn(II)$ and Z_1 is O
 N
 N
or N

10. A compound according to claim 9, containing branched C_3 - C_{24} alkyl or branched C_3 - C_{24} alkenyl.

11. A compound according to claim 9 or 10 of formula (I), wherein

$$\begin{array}{c} Q_{1} & G_{1} \\ A_{1} & N - \\ R_{1} & R_{2} \end{array}$$

INTERNATIONAL SEARCH REPORT

International Application No PCT/EP2004/050185

A. CLASSIF IPC 7	G11B7/24 C07D403/02				
According to International Patent Classification (IPC) or to both national classification and IPC					
B. FIELDS			1.207		
Minimum do IPC 7	cumentation searched (classification system followed by classification $G11B - C07D$	n symbols)			
	ion searched other than minimum documentation to the extent that su				
	ata base consulted during the International search (name of data bas				
EPO-In	ternal, WPI Data, PAJ, CHEM ABS Data				
C. DOCUME	ENTS CONSIDERED TO BE RELEVANT				
Category °	Citation of document, with indication, where appropriate, of the rele	evant passages	Relevant to claim No.		
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ŧ					
Further documents are listed in the continuation of box C. Patent family members are listed in annex.					
° Special ca	degories of cited documents :	"T" later document published after the Inter	rnational filing date		
'A' document defining the general state of the art which is not or priority date and not in conflict with the application but clied to understand the principle or theory underlying the					
considered to be of particular relevance invention *E* earlier document but published on or after the international filling date. *X* document of particular relevance; the claimed invention					
filing date cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone which is cited to establish the publication date of another cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone cannot be considered novel or					
which is clied to establish the publication date of another citation or other special reason (as specified) "O" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such docu—					
other means such combination being obvious to a person skilled					
later than the priority date claimed "&" document member of the same patent family					
Date of the actual completion of the international search Date of mailing of the international search report					
12 July 2004		21/07/2004			
Name and mailing address of the ISA European Patent Office, P.B. 5818 Patentlaan 2 Authorized officer					
NL – 2280 HV Rijswijk Tel. (+31–70) 340–2040, Tx. 31 651 epo nl, Fax: (+31–70) 340–3016		Vanhecke, H			

INTERNATIONAL SEARCH REPORT

Information on patent family members

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DERWENT-ACC-NO: 2004-728406

DERWENT-WEEK: 200735

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TITLE: Optical recording medium, e.g. compact disc for

computer, includes recording layer comprising (new) transition metal complex of nitrogen-

containing heterocyclic ligand

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BUDRY, J L

PATENT-ASSIGNEE: CIBA SC HOLDING AG[CIBA] , CIBA SPECIALITY

CHEM HOLDING INC[CIBA] , CIBA SPECIALTY CHEM HOLDING INC[CIBA] , BUDRY J[BUDRI] , LEHMANN U

[LEHMI] , SCHMIDHALTER B[SCHMI] , SUTTER P

[SUTTI]

PRIORITY-DATA: 2003CH-0000331 (March 3, 2003)

PATENT-FAMILY:

PUB-NO	PUB-DATE	LANGUAGE	PAGES	MAIN-IPC
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DESIGNATED-STATES: AE AG AL AM AT AU AZ BA BB BG BR BW BY BZ CA CH CH CH CN CO CR CU CZ DE DK DM DZ EC EE EG ES FI GB GD GE GH GM HR HU ID IL IN IS JP KE KG KP KR KZ LC LK LR LS LT LU LV MA MD MG MK MN MW MX MZ NA NI NO NZ OM PG PH PL P T RO RU SC SD SE SG SK SL SY TJ TM TN TR TT TZ UA UG US UZ VC VN YU ZA ZM ZW AT BE BG BW CH CY CZ DE DK EA EE ES FI FR GB GH GM GR HU IE IT KE LS LU MC MW MZ NL OA PT RO SD SE SI SK SL SZ TR TZ UG ZM ZW AT BE BG CH CY CZ DE DK EE ES FI FR GB GH GM GR HU IE IT KE ES FI FR GB GR HU IE IT LI LU LV MC MK NL PT RO SE SI SK TR AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HU IE IT LI LU LV MC MK NL PT RO SE SI SK TR AT BE BG CH CY CZ DE DK EE ES SI SK TR AT BE BG CH CY CZ DE DK EE ES SI SK TR AT BE BG CH CY CZ DE DK EE ES SI SK TR AT BE BG CH CY CZ DE DK EE

APPLICATION-DATA:

PUB-NO	APPL-DESCRIPTOR	APPL-NO	APPL-DATE
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IN 200502505P4	N/A	2005IN-CN02505	October 3, 2005
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DE6004001135T2	Based on	WO2004079732	N/A

RELATED-ACC-NO: 2005-664282

ABSTRACTED-PUB-NO: WO2004079732A

BASIC-ABSTRACT:

NOVELTY - An optical recording medium comprises a substrate, a recording layer and optionally reflecting layer(s). The

recording layer comprises transition metal complex (I) of nitrogen-containing heterocyclic ligand, or its tautomer, some of which are new.

DETAILED DESCRIPTION - An optical recording medium comprises a substrate, a recording layer and optionally reflecting layer(s). The recording layer comprises a complex of formula (I) or its tautomer.

G1, G2 = a group of structures (IX)-(XII);

A1, A2 = N(R12), O, S or Se;

A3 = C(1-5C alkyl)2, C(4-5C alkylene), N(R12), O, S, Se, N=C (R13) or unsubstituted or R14-substituted CH=CH;

M1 = transition metal of groups IX-XII, preferably Co, Cu, Ni, Pd or Zn;

Q1, Q2 = C(R15), N or P;

R1-R8, R14 = H, R18, 6-12C aryl, 4-12C heteroaryl, 7-12C aralkyl or 5-12C heteroaralkyl, each optionally substituted by radicals R18;

R9, R12, R13 = 1-24C alkyl, 3-24C cycloalkyl, 2-24C alkenyl, 3-24C cycloalkenyl, 1-4C alkyl-(O-1-4C alkylene)O-1-4C alkylene)m or 1-4C alkyl-(NH-1-4C alkylene)m, each of which substituted by radicals R17; or 6-12C aryl, 4-12C heteroaryl, 7-12C aralkyl or 5-12C heteroaralkyl, each optionally substituted by radicals R18;

R10, R11, R18 = halo, nitro, cyano, thiocyano, hydroxy, O-R19, O-CO-R19, S-R19, CHO, COR20, CHOR19OR23, CR20OR19OR23, R16, N=N-R16, N=CR19R20, N=CR21R22, C(R15)=NR19, C(R15)=NR21, C(R15) = CR21R22, NH2, NH-R19, NR19R20, N=CR21R22, C(R15)=NR19, C(R15) = NR21, C(R15)=NR21R22, NH2, NH-R19, NR19R21, NH3+, NH2R19+, NH2R19R20+, NR19R20R23+, CONH2, CONHR19, CONR19R20, SO2R19, SO2NH2, SO2NH19, SO2NR19R20, COOH, COOR19, OCOOR19, NHCOR19, NR19COR23, NHCOOR19, NR19COOR23, ureido, NR19-CO-NHR23, B(OH)2, B (OH) (OR19), B (OR19)OR23, phosphato, PR19R23, POR19OR23, P(=O) OR19OR23, OPR19R23, OPR19OR23, OP(=O)R19OR23, OP(=O)OR19OR23, OPO3R19, sulfato, sulfo or 1-12C alkyl, 3-12C cycloalkyl, 1-12C alkylthio, 3-12C cycloalkylthio, 3-12C alkoxy or 3-12C cycloalkoxy, each optionally substituted by radicals R17;

R15 = H, cyano, hydroxy, 1-12C alkoxy, 3-12C cycloalkoxy, 1-12C alkylthio, 3-12C cycloalkylthio, amino, NHR24, NR25R26, R27, halo, nitro, formyl, N=N-R27, C(R14)=CR21R22, C(R14)=NR19, COO-R25, carboxy, carbamoyl, CONH-R25, CONR25R26, N=CR19R20, or 1-12C alkyl, 3-12C cycloalkyl, 2-12C alkenyl or 3-12C cycloalkenyl each optionally substituted by halo, hydroxy, 1-12C alkoxy or 3-12C cycloalkoxy;

R16 = 6-12C aryl, 4-12C heteroaryl, 7-12C aralkyl or 5-12C heteroaralkyl, each optionally substituted by radical R29;

R17 = halo, hydroxy, O-R25, O-CO-R25, S-R25, NH2, NH-R25, NR25R26, NH3+, NH2R25+, NHR25R26+, NR24R25R26+, NR25-CO-R24, NR25COOR24, cyano, formyl, COO-R25, carboxy, carbamoyl, CONH-R25, CONR25R26, ureido, NH-CO-NHR24, NR25-CO-NHR24, phosphato, PR25R24, POR25OR24, P(=0) OR25OR24, OPR25R24, OPR25OR24, OP(=0) R25OR24, OP(=0) OR25OR24, SO2R25, sulfato, sulfo, R27, N=N-R27 or 1-12C alkoxy or 1-12C cycloalkoxy each unsubstituted or mono- or poly-substituted by halo;

R19, R20, R23 = R16, or 1-12C alkyl, 3-12C cycloalkyl, 2-12C alkenyl, or 3-12C cycloalkenyl, each optionally substituted by halo, hydroxy, 1-12C alkoxy or 3-12C cycloalkoxy;

R21, R22 = NR25R26, CN, CONH2, CONHR19, CONR19R20 or COOR20;

R24-R26 = 1-12 alkyl, 3-12C cycloalkyl, 2-12C alkenyl, 3-12C cycloalkenyl, 6-12C aryl, 4-12C heteroaryl, 7-12C aralkyl or 5-12C heteroaralkyl;

R27 = 6-12C alkyl, 4-12C heteroalkyl, 7-12C aralkyl, or 5-12C heteroaralkyl, each optionally substituted by radicals R18;

R28 = nitro, SO2NHR25, SO2NR25R26, 1-12C alkyl, 3-12C cycloalkyl, 1-12C alkylthio, 3-12C cycloalkylthio, 1-12C alkoxy or 3-12C cycloalkoxy, each optionally substituted by radicals R17;

m = 1-10.

Optionally, R1+R2, R3+R4, R5+R6, R5+R13 and/or R5+R14 together in pairs are 3-6C alkylene or 3-6C alkenylene, each of which is optionally substituted by radicals R17 and may be interrupted by 0, S or N(R12), or 1, 4-buta-1, 3-dienylene, groups of structure (1) or (2), each optionally substituted by radical R18 and in which 1 or 2 carbon atoms may have been replaced by nitrogen. R14

+R19, R15+R19 and/or R19+R23 together are 3-12C cycloalkyl, 2-12C alkenyl or 3-12C cycloalkenyl, each optionally substituted by halo, hydroxy, 1-12C alkoxy or 3-12C cycloalkoxy. R19+R20 together with the common nitrogen are pyrrolidine, piperidine, piperazine, or morpholine, each unsubstituted or mono- to tetrasubstituted by 1-4C alkyl; or cabazole, phenoxazine or phenothiazine, each optionally substituted by radicals R28. R25+R26 together with the common nitrogen are pyrrolidine, piperidine, piperazine or morpholine, each unsubstituted, or mono- to tetra-substituted by 1-4C alkyl.

INDEPENDENT CLAIMS are also included for:

- (1) a method of recording or playing back data comprising recording or playing back the data on the optical recording medium at a wavelength of 350-500 nm; and
- (2) new compounds (I) with the exception of those disclosed in J. Org. Chem. 67/16 5753-5772 (2002).

The new (I) are not e.g. compounds of formula M2(Z1)2 where M2 is Co(II), Cu(II), Hg(II), Ni(II), Pd(II) or Zn(II) and Z1 is a group of formula (a).

or where M2 is Co(II), Cu(II), Ni(II), Pd(II) or Zn(II) and Z1 is a group of formula (b)-(f).

Many other combinations of excluded metals and ligands are specified.

USE - The recording medium, e.g. compact disc or digital video disc, is used in computers and as storage material for identification and security cards or for the production of optical elements, e.g. holograms.

ADVANTAGE - The optical recording materials have excellent recording and playback quality especially at a wavelength of 350-500 nm. Recording and playback can be effected very advantageously with high sensitivity at the same wavelength, and the storage density is higher than in the case of known materials. The materials have very good storage properties before and after recording, even under especially harsh conditions, e.g. exposure to sunlight or fluorescent lighting, heat and/or high humidity. The manufacture is simple and readily reproducible using customary coating processes, e.g. spincoating. The optical recording medium has high information

density, sensitivity and data reliability. It is robust, durable and easy to use. It is inexpensive to manufacture.

CHOSEN-DRAWING: Dwg.0/0

TITLE-TERMS: OPTICAL RECORD MEDIUM COMPACT DISC COMPUTER

RECORD LAYER COMPRISE NEW TRANSITION METAL COMPLEX NITROGEN CONTAIN HETEROCYCLE LIGAND

DERWENT-CLASS: E12 L03 P73 P75 T03

CPI-CODES: E05-L; E05-M; E05-N; L03-G04B; **EPI-CODES:** T03-B01B1; T03-B01D1; T03-B01D3;

CHEMICAL-CODES: Chemical Indexing M3 *01* Fragmentation Code

A429 A960 C710 D012 D019 D022 D029 E600 E699 K0

L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M282 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds

AFHU8K AFHU8U

Chemical Indexing M3 *02* Fragmentation Code A429 A960 C710 D012 D019 E600 E699 K0 L3 L355 L9 L922 L999 M1 M126 M143 M280 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHUAK AFHUAU

Chemical Indexing M3 *03* Fragmentation Code A429 A960 C710 D012 D019 D022 D029 E400 E499 H7 H720 M1 M126 M132 M210 M214 M233 M240 M282 M311 M321 M343 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHUCK AFHUCU

Chemical Indexing M3 *04* Fragmentation Code A428 A960 C710 D012 D019 D022 D029 E600 E699 H5 H542 H8 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M272 M282 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHULK AFHULU

Chemical Indexing M3 *05* Fragmentation Code A429 A960 C710 D012 D019 D022 D029 E600 E699 H5 H542 H8 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M272 M282 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHUNK AFHUNU Chemical Indexing M3 *06* Fragmentation Code A429 A960 C316 C710 D012 D019 D022 D029 E600 E699 H7 H720 K0 K4 K442 K499 M1 M126 M132 M210 M212 M271 M282 M311 M321 M343 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHURK AFHURU

Chemical Indexing M3 *07* Fragmentation Code A427 A960 C710 D012 D019 D022 D029 E600 E699 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M282 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHUTK AFHUTU

Chemical Indexing M3 *08* Fragmentation Code A427 A960 C710 D012 D019 D022 D029 E600 E699 H5 H542 H8 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M272 M282 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHUXK AFHUXU

Chemical Indexing M3 *09* Fragmentation Code A428 A960 C710 D012 D019 D022 D029 E600 E699 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M282 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHVOK AFHVOU

Chemical Indexing M3 *10* Fragmentation Code A428 A960 C316 C710 D012 D019 D022 D029 E400 E499 H7 H720 K0 K4 K442 K499 M1 M126 M132 M210 M212 M271 M282 M311 M321 M343 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHV1K AFHV1U

Chemical Indexing M3 *11* Fragmentation Code A427 A960 C710 F012 F014 F019 F710 F799 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M282 M320 M411 M510 M522 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHV9K AFHV9U

Chemical Indexing M3 *12* Fragmentation Code A428 A960 C710 D012 D019 D022 D029 E600 E699 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M214 M233 M240 M282 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHVBK AFHVBU

Chemical Indexing M3 *13* Fragmentation Code A429 A960 C710 D012 D019 D022 D029 E600 E699 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M214 M233 M240 M282 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHVDK AFHVDU

Chemical Indexing M3 *14* Fragmentation Code A427 A960 C710 D012 D019 D022 D029 E600 E699 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M214 M233 M240 M282 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHVLK AFHVLU

Chemical Indexing M3 *15* Fragmentation Code A428 A960 C710 F012 F014 F019 F710 F799 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M282 M320 M411 M510 M522 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHVNK AFHVNU

Chemical Indexing M3 *16* Fragmentation Code A427 A960 C710 D012 D019 D022 D029 E400 E499 H7 H720 M1 M126 M132 M210 M214 M233 M240 M282 M311 M321 M343 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHVPK AFHVPU

Chemical Indexing M3 *17* Fragmentation Code A429 A960 C710 F012 F014 F019 F710 F799 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M281 M320 M411 M510 M522 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHVWK AFHVWU

Chemical Indexing M3 *18* Fragmentation Code A428 A960 C710 F012 F014 F019 F710 F799 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M281 M320 M411 M510 M522 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHW1K AFHW1U

Chemical Indexing M3 *19* Fragmentation Code A427 A960 C710 F012 F014 F019 F710 F799 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M281 M320 M411 M510 M522 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHW6K AFHW6U

Chemical Indexing M3 *20* Fragmentation Code A428 A960 C710 D012 D019 E400 E499 H7 H720 M1 M126 M132 M280 M311 M321 M343 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHW8K AFHW8U

Chemical Indexing M3 *21* Fragmentation Code A428 A960 C710 D012 D019 D022 D029 E400 E499 H7 H720 M1 M126 M132 M210 M214 M233 M240 M282 M311 M321 M343 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHW9K AFHW9U

Chemical Indexing M3 *22* Fragmentation Code A427 A960 C710 D012 D019 E400 E499 H7 H720 M1 M126 M132 M280 M311 M321 M343 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHWCK AFHWCU

Chemical Indexing M3 *23* Fragmentation Code A427 A960 C710 D012 D019 E600 E699 K0 L3 L355 L9 L922 L999 M1 M126 M143 M280 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHWDK AFHWDU

Chemical Indexing M3 *24* Fragmentation Code A428 A960 C710 D012 D019 E600 E699 K0 L3 L355 L9 L922 L999 M1 M126 M143 M280 M320 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHWFK AFHWFU

Chemical Indexing M3 *25* Fragmentation Code A429 A960 C710 D012 D019 E400 E499 H7 H720 M1 M126 M132 M280 M311 M321 M343 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHWGK AFHWGU

Chemical Indexing M3 *26* Fragmentation Code A428 A960 C710 D012 D019 E400 E499 H7 H720 M1

M126 M132 M280 M312 M321 M331 M340 M343 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHWHK AFHWHU

Chemical Indexing M3 *27* Fragmentation Code A427 A960 C710 D012 D019 E400 E499 H7 H720 M1 M126 M132 M280 M312 M321 M331 M340 M343 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHWIK AFHWIU

Chemical Indexing M3 *28* Fragmentation Code A429 A960 C710 D012 D019 E400 E499 H7 H720 M1 M126 M132 M280 M312 M321 M331 M340 M343 M411 M512 M520 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHWLK AFHWLU

Chemical Indexing M3 *29* Fragmentation Code A429 A960 C710 F012 F014 F019 F710 F799 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M282 M320 M411 M510 M522 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHWMK AFHWMU

Chemical Indexing M3 *30* Fragmentation Code A428 A960 C710 F012 F015 F019 F710 F799 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M282 M320 M411 M510 M522 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHWNK AFHWNU

Chemical Indexing M3 *31* Fragmentation Code A427 A960 C710 F012 F015 F019 F710 F799 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M282 M320 M411 M510 M522 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHWOK AFHWOU

Chemical Indexing M3 *32* Fragmentation Code A429 A960 C710 F012 F015 F019 F710 F799 K0 L3 L355 L9 L922 L999 M1 M126 M143 M210 M211 M240 M282 M320 M411 M510 M522 M530 M540 M630 M781 M904 M905 Q454 R043 Specfic Compounds AFHWPK AFHWPU

Chemical Indexing M3 *33* Fragmentation Code A427 A428 A429 A430 A546 A960 B605 B615 B634

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F015 F016 F017 F019 F020 F022 F029 F421 F422
F423 F431 F432 F511 F512 F521 F522 F523 F530
F541 F542 F570 F580 F599 F610 F630 F699 F710
F730 F799 G001 G002 G010 G011 G012 G013 G019
G020 G021 G022 G029 G030 G031 G032 G039 G040
G050 G051 G052 G100 G111 G112 G113 G221 G299
G553 G563 H100 H101 H103 H121 H122 H123 H161
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H401 H402 H403 H404 H405 H421 H422 H423 H424
H521 H522 H523 H592 H599 H600 H607 H608 H609
H621 H622 H623 H721 J011 J012 J013 J014 J111
J112 J113 J211 J212 J221 J222 J311 J312 J411
J412 J581 J582 J583 K421 K431 K499 K534 K599
L120 L142 L199 L355 L399 L472 L499 L640 L650
L660 L699 L722 L724 L910 L921 L922 L941 L943
L999 M1 M113 M115 M116 M119 M123 M125 M126 M129
M132 M135 M139 M141 M142 M143 M144 M149 M150
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M222 M223 M224 M225 M226 M231 M232 M233 M240
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M311 M312 M313 M314 M315 M316 M320 M321 M322
M323 M331 M332 M333 M340 M342 M343 M373 M391
M392 M393 M411 M510 M511 M521 M522 M523 M530
M531 M532 M533 M540 M541 M542 M543 M630 M781
M904 M905 Q454 R043 Ring Index 00085 00090
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Markush Compounds 200140-51401-K 200140-51401-U
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CPI Secondary Accession Numbers: C2004-255905 Non-CPI Secondary Accession Numbers: N2004-576927